NSN 5961-00-904-4949

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-904-4949 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.209 inches and 0.230 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakover voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 1 threaded stud and 3 uninsulated wire lead **Specification Data:** 80131-release4717 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0